



# DATA SHEET

## Hall Effect Current Sensor

PN: CHK\_EKB15D4

IPN=200-2000A

### Feature

- Open-loop
- Capable measurement of currents: DC, AC,pulse with galvanic isolation between primary circuit and secondary circuit.
- Supply voltage: DC ±12~15V
- Removable structure

### Advantages

- Excellent accuracy
- Easy installation
- No insertion losses
- Low power consumption
- Wide current measuring range
- High immunity to external interference
- Very good linearity
- Can be customized



### Electrical data: (Ta=25°C, Vc=±15.0VDC, RL=10KΩ)

| Parameter                               | Ref                      | CHK100<br>EKB15D4 | CHK200<br>EKB15D4 | CHK400<br>EKB15D4 | CHK800<br>EKB15D4 | CHK1000<br>EKB15D4 | CHK1200<br>EKB15D4 | CHK2000<br>EKB15D4 |
|---|--------------------------|-------------------|-------------------|-------------------|-------------------|--------------------|--------------------|--------------------|
| Rated input Ipn(A)                      |                          | 100               | 200               | 400               | 800               | 1000               | 1200               | 2000               |
| Measuring range Ip(A)                   |                          | 0~±300            | 0~±600            | 0~±1200           | 0~±2400           | 0~±3000            | 0~±3600            | 0~±4000            |
| Output voltage Vo(V)                    | $\pm 4.0^*(IP/IPN)$      |                   |                   |                   |                   |                    |                    |                    |
| Load resistance RL(KΩ)                  | >10                      |                   |                   |                   |                   |                    |                    |                    |
| Supply voltage VC(V)                    | (±12~±15) ±5%            |                   |                   |                   |                   |                    |                    |                    |
| Accuracy XG(%)                          | @IPN, T=25°C <±1.0       |                   |                   |                   |                   |                    |                    |                    |
| Offset voltage VOE(mV)                  | @IP=0, T=25°C <±25       |                   |                   |                   |                   |                    |                    |                    |
| Temperature variation of VOE VOT(mV/°C) | @IP=0, -40 ~ +85°C <±1.0 |                   |                   |                   |                   |                    |                    |                    |
| Hysteresis offset voltage VOH(mV)       | @IP=0, after 1*IPN <±25  |                   |                   |                   |                   |                    |                    |                    |
| Linearity error er(%FS)                 | < 1.0                    |                   |                   |                   |                   |                    |                    |                    |
| Di/dt accurately followed (A/μs)        | > 100                    |                   |                   |                   |                   |                    |                    |                    |
| Response time tra(μs)                   | @90% of IPN <5.0         |                   |                   |                   |                   |                    |                    |                    |
| Power consumption IC(mA)                | 15                       |                   |                   |                   |                   |                    |                    |                    |



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|                           |                   |       |
|---------------------------|-------------------|-------|
| Bandwidth Bw(KHZ)         | @-3dB, IPN        | DC-20 |
| Insulation voltage Vd(KV) | @50/60Hz, 1min,AC | 3.0   |

## General data:

| Parameter                    | Value   |
|------------------------------|---|
| Operating temperature TA(°C) | -40 ~ +85                                       |
| Storage temperature TS(°C )  | -55~ +125                                       |
| Mass M(g )                   | 120   |
| Plastic material             | PBT G30/G15, UL94- V0;                          |
| Standards                    | IEC60950-1:2001<br>EN50178:1998<br>SJ20790-2000 |

## Dimensions(mm):

| CHK-EKB15D4M   | CHK-EKB15D4S | Connection |
|--|--------------|------------|
|  |              |            |
| General tolerance  |              |            |
| General tolerance:< ±0.5mm   |              |            |
| Primary through-hole : D40.5±0.20  |              |            |
| Connection of Secondary :<br>CHK-EKB15D4M:<br>2510-04A (Instead of Molex 5045-04A)<br>CHK-EKB15D4S: 15EDGK3.81-04P |              |            |

## Remarks:

- When the current goes through the primary pin of a sensor, the voltage will be measured at the output end.
- Custom design is available for the different rated input current and the output voltage.
- The dynamic performance is the best when the primary hole if fully filled with.
- The primary conductor should be <100°C.

**WARNING : Incorrect wiring may cause damage to the sensor.**

